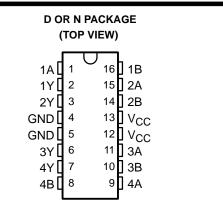
## 74ACT11810 QUADRUPLE 2-INPUT EXCLUSIVE-NOR GATE

SCAS211 - MARCH 1990 - REVISED APRIL 1993

- Inputs Are TTL-Voltage Compatible
- Flow-Through Architecture to Optimize PCB Layout
- Center-Pin V<sub>CC</sub> and GND Configurations to Minimize High-Speed Switching Noise
- EPIC<sup>™</sup> (Enhanced-Performance Implanted CMOS) 1-µm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- Package Options Include Plastic Small-Outline Packages and Standard Plastic 300-mil DIPs



#### description

This device contains four independent Exclusive-NOR gates. They perform the Boolean functions  $Y = \overline{A \oplus B} = (A + \overline{B}) \bullet (\overline{A} + B)$  in positive logic.

A common application is a true/complement element. If one of the inputs is high, the other input will be reproduced in true form at the output. If one of the inputs is low, the signal on the other input will be reproduced inverted at the output.

The 74ACT11810 is characterized for operation from  $-40^{\circ}$ C to  $85^{\circ}$ C.

**FUNCTION TABLE** 

INP	UTS	OUTPUT
Α	В	Υ
L	L	Н
L	Н	L
Н	L	L
Н	Н	Н

EPIC is a trademark of Texas Instruments Incorporated.

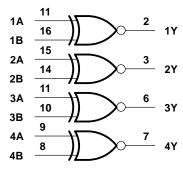


SCAS211 - MARCH 1990 - REVISED APRIL 1993

#### logic symbol†

#### 1A = 1 16 1B 15 2A 3 14 2B 11 **3A** 6 10 3B 9 4A 7 8 4B

#### logic diagram (positive logic)



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V <sub>CC</sub>	0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, V <sub>O</sub> (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ )	± 20 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )	± 50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	± 50 mA
Continuous current through V <sub>CC</sub> or GND	± 100 mA
Storage temperature range	

<sup>&</sup>lt;sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

#### recommended operating conditions

		MIN	MAX	UNIT
Vcc	Supply voltage	4.5	5.5	V
VIH	High-level input voltage	2		٧
V <sub>IL</sub>	Low-level input voltage		0.8	٧
٧ <sub>I</sub>	Input voltage	0	VCC	V
VO	Output voltage	0	VCC	V
ЮН	High-level output current		-24	mA
lOL	Low-level output current		24	mA
Δt/Δν	Input transition rise or fall rate	0	10	ns/V
TA	Operating free-air temperature	- 40	85	ô

<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 andIEC Publication 617-12.

SCAS211 - MARCH 1990 - REVISED APRIL 1993

## electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	vcc	T <sub>A</sub> = 25°C			MIN	MAY	UNIT
	TEST CONDITIONS		MIN	TYP	MAX	MIN	MAX	UNII
	IOH = - 50 μA	4.5 V	4.4			4.4		
		5.5 V	5.4			5.4		V
Voн	I <sub>OH</sub> = -24 mA	4.5 V	3.94			3.8		
		5.5 V	4.94			4.8		
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V				3.85	85	
	I <sub>OL</sub> = 50 μA	4.5 V			0.1		0.1	
		5.5 V			0.1		0.1	
VOL	I <sub>OL</sub> = 24 mA	4.5 V			0.36		0.44	V
		5.5 V			0.36		0.44	
	$I_{OL} = 75 \text{ mA}^{\dagger}$	5.5 V					1.65	
lį	$V_I = V_{CC}$ or GND	5.5 V			± 0.1		±1	μΑ
Icc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V			4		4	μΑ
Δl <sub>CC</sub> ‡	One input at 3.4 V, Other inputs at GND or V <sub>CC</sub>	5.5 V			0.9		1	mA
C <sub>i</sub>	$V_I = V_{CC}$ or GND	5 V		3.5				pF

<sup>†</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

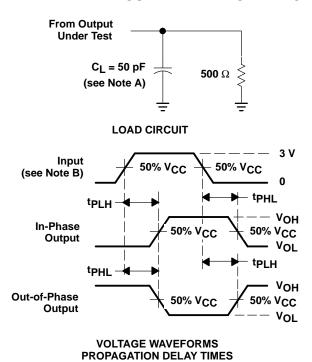
PARAMETER	FROM (INPUT)	TO (OUTPUT)	T <sub>A</sub> = 25°C			Adibi	MAY	UNIT
			MIN	TYP	MAX	MIN	MAX	UNII
<sup>t</sup> PLH	A or B	V	1.9	4.8	7.2	1.9	8.3	
<sup>t</sup> PHL	(other input low)	ĭ	1.9	4.9	7.1	1.9	8.3	ns
<sup>t</sup> PLH	A or B (other input high)	V	1.9	4.8	7.2	1.9	8.3	20
t <sub>PHL</sub>		1	1.9	4.9	7.1	1.9	8.3	ns

### operating characteristics, $V_{CC}$ = 5 V, $T_A$ = 25°C

PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub> Power dissipation capacitance	$C_L = 50 \text{ pF},  f = 1 \text{ MHz}$	26	pF

<sup>‡</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or VCC.

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

B. Input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ ,  $t_f \leq$  2.5 ns,  $t_f \leq$  2.5 ns.

C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

#### **IMPORTANT NOTICE**

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.

Copyright © 1996, Texas Instruments Incorporated